



PXN012-60QL

N-channel 60 V, 11.5 mOhm, logic level Trench MOSFET in MLPAK33

8 July 2021

Product data sheet

1. General description

General purpose, 42 A rated, logic level N-channel enhancement mode Power MOSFET in MLPAK33 package.

2. Features and benefits

- Logic level compatibility
- Trench MOSFET technology
- Thermally efficient package in a small form factor (3.3 mm x 3.3 mm footprint)

3. Applications

- Secondary side synchronous rectification
- DC-to-DC converters
- Motor drive
- LED lighting
- Load switching
- Auxiliary control
- Fan control

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | | Min | Typ | Max | Unit |
|-------------------------|--|---|---------------------|-----|------|------|------|
| V _{DS} | drain-source voltage | 25 °C ≤ T _j ≤ 150 °C | | - | - | 60 | V |
| I _D | drain current | V _{GS} = 10 V; T _{sp} = 25 °C; Fig. 2 | | - | - | 42 | A |
| P _{tot} | total power dissipation | T _{sp} = 25 °C; Fig. 1 | | - | - | 34.7 | W |
| T _j | junction temperature | | | -55 | - | 150 | °C |
| Static characteristics | | | | | | | |
| R _{DSon} | drain-source on-state resistance | V _{GS} = 10 V; I _D = 10 A; T _j = 25 °C; Fig. 9 | | - | 9.8 | 11.5 | mΩ |
| | | V _{GS} = 4.5 V; I _D = 10 A; T _j = 25 °C; Fig. 9 | | - | 14 | 17.6 | mΩ |
| Dynamic characteristics | | | | | | | |
| Q _{GD} | gate-drain charge | I _D = 10 A; V _{DS} = 30 V; V _{GS} = 4.5 V; T _j = 25 °C; Fig. 11 ; Fig. 12 | | - | 4.3 | - | nC |
| Q _{G(tot)} | total gate charge | | | - | 9.64 | - | nC |
| Avalanche ruggedness | | | | | | | |
| E _{DS(AL)S} | non-repetitive drain-source avalanche energy | I _D = 3.5 A; T _{j(init)} = 25 °C; unclamped | [1] | - | - | 90 | mJ |

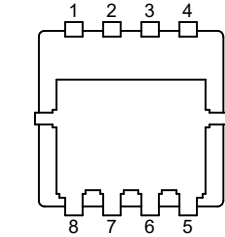
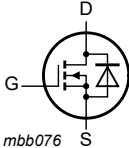
N-channel 60 V, 11.5 mOhm, logic level Trench MOSFET in MLPAK33

| Symbol | Parameter | Conditions | | Min | Typ | Max | Unit |
|--------------------|------------------|---|-----|-----|-----|-----|------|
| Source-drain diode | | | | | | | |
| Q_r | recovered charge | $I_S = 10\text{ A}$; $dI_S/dt = -100\text{ A}/\mu\text{s}$; $V_{GS} = 0\text{ V}$; $V_{DS} = 30\text{ V}$; $T_J = 25\text{ }^\circ\text{C}$; Fig. 15 | [2] | - | 13 | - | nC |

[1] Protected by 100% test
[2] includes capacitive recovery

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-------------|--|---|
| 1 | S | source |  MLPAK33 (SOT8002-1) |  mbb076 |
| 2 | S | source | | |
| 3 | S | source | | |
| 4 | G | gate | | |
| 5 | D | drain | | |
| 6 | D | drain | | |
| 7 | D | drain | | |
| 8 | D | drain | | |

6. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|-------------|---------|---|-----------|
| | Name | Description | Version |
| PXN012-60QL | MLPAK33 | plastic thermal enhanced surface mounted package; mini leads; 8 terminals; pitch 0.65 mm; 3.3 x 3.3 x 0.8 mm body | SOT8002-1 |

7. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| PXN012-60QL | 7AB |

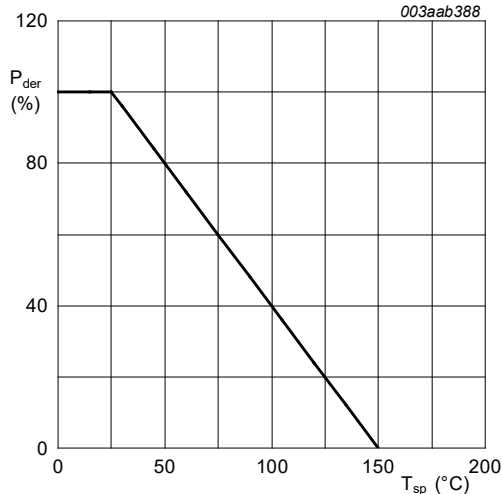
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

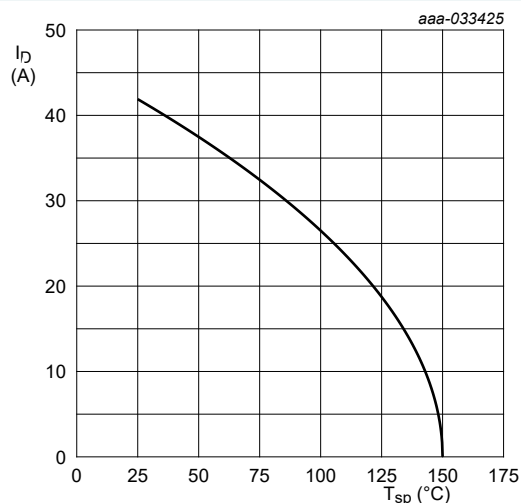
| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------------------------|--|---|-----|------|-------|
| V_{DS} | drain-source voltage | $25\text{ °C} \leq T_J \leq 150\text{ °C}$ | - | 60 | V |
| V_{GS} | gate-source voltage | | -20 | 20 | V |
| P_{tot} | total power dissipation | $T_{sp} = 25\text{ °C}$; Fig. 1 | - | 34.7 | W |
| I_D | drain current | $V_{GS} = 10\text{ V}$; $T_{sp} = 25\text{ °C}$; Fig. 2 | - | 42 | A |
| | | $V_{GS} = 10\text{ V}$; $T_{sp} = 100\text{ °C}$; Fig. 2 | - | 26 | A |
| I_{DM} | peak drain current | pulsed; $t_p \leq 10\text{ }\mu\text{s}$; $T_{sp} = 25\text{ °C}$; Fig. 3 | - | 168 | A |
| T_{stg} | storage temperature | | -55 | 150 | °C |
| T_J | junction temperature | | -55 | 150 | °C |
| $T_{sld(M)}$ | peak soldering temperature | | - | 260 | °C |
| Source-drain diode | | | | | |
| I_S | source current | $T_{sp} = 25\text{ °C}$ | - | 29 | A |
| I_{SM} | peak source current | pulsed; $t_p \leq 10\text{ }\mu\text{s}$; $T_{sp} = 25\text{ °C}$ | - | 168 | A |
| Avalanche ruggedness | | | | | |
| $E_{DS(AL)S}$ | non-repetitive drain-source avalanche energy | $I_D = 3.5\text{ A}$; $T_{J(\text{init})} = 25\text{ °C}$; unclamped | [1] | - | 90 mJ |
| I_{AS} | non-repetitive avalanche current | $T_{J(\text{init})} = 25\text{ °C}$ | [1] | - | 3.5 A |

[1] Protected by 100% test



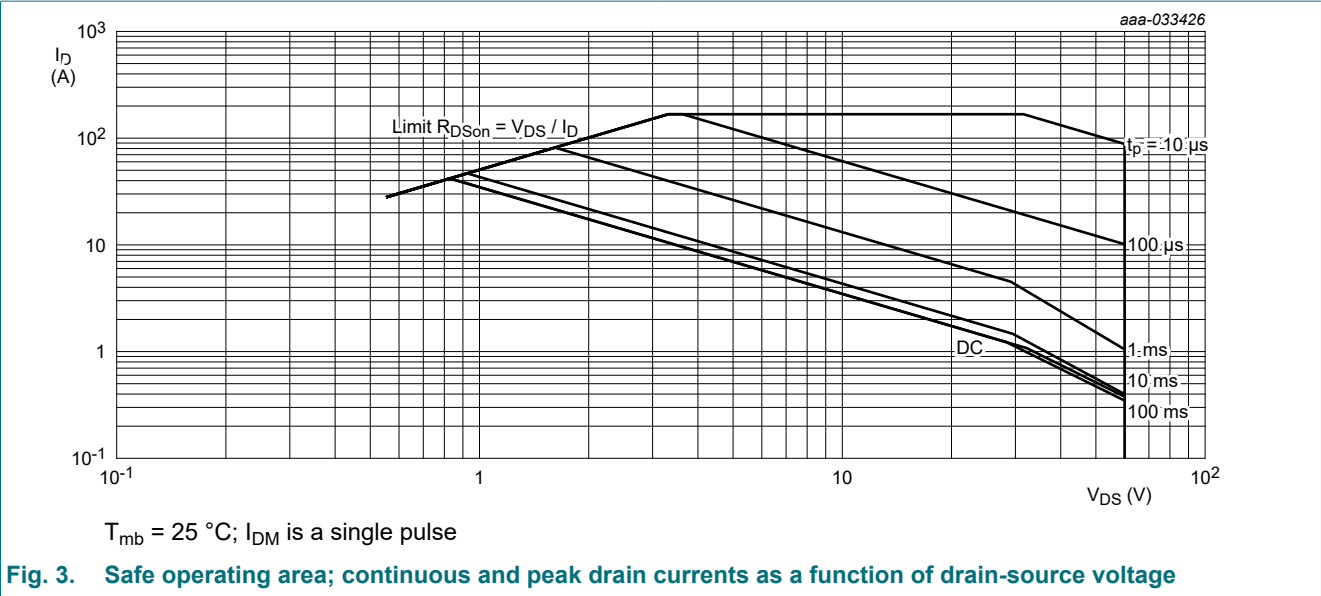
$$P_{der} = \frac{P_{tot}}{P_{tot(25^\circ\text{C})}} \times 100\%$$

Fig. 1. Normalized total power dissipation as a function of solder point temperature



$V_{GS} \geq 10\text{ V}$

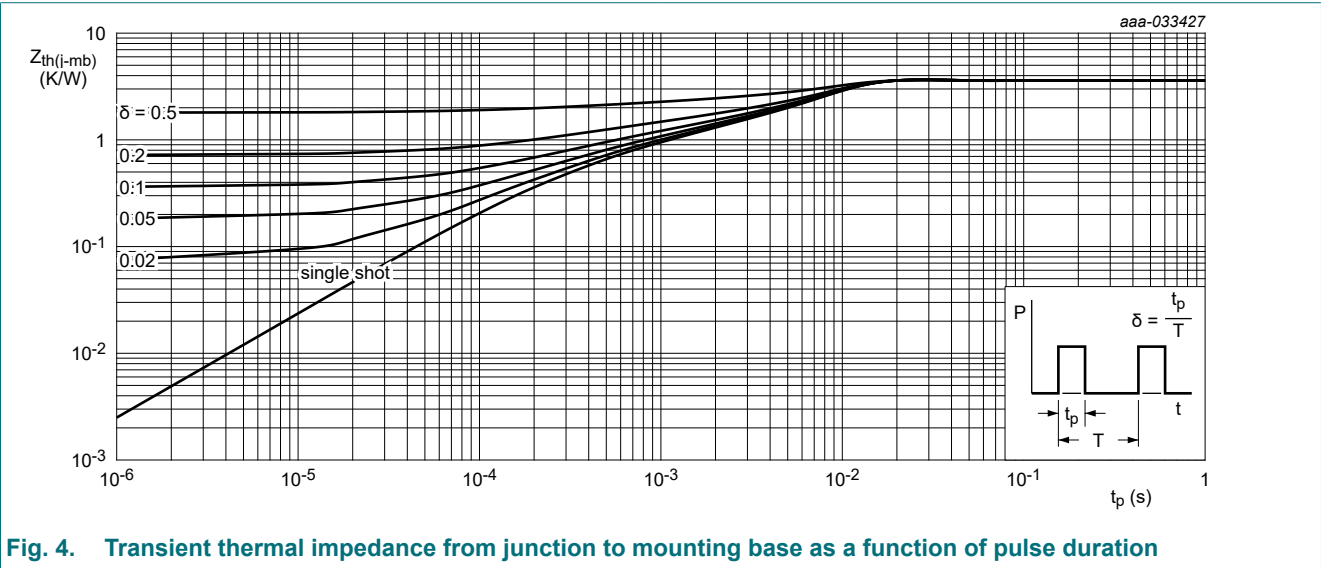
Fig. 2. Continuous drain current as a function of mounting base temperature



9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------------|--|------------|-----|-----|-----|------|
| $R_{th(j-sp)}$ | thermal resistance from junction to solder point | Fig. 4 | - | 3 | 3.6 | K/W |



10. Characteristics

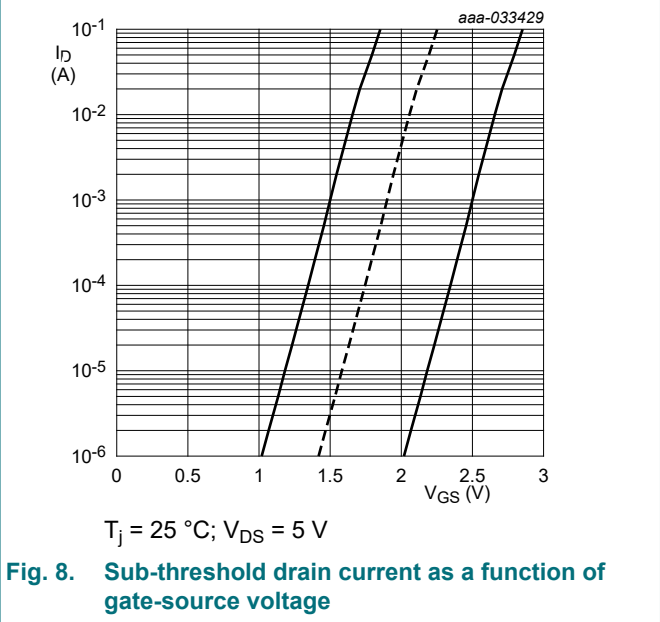
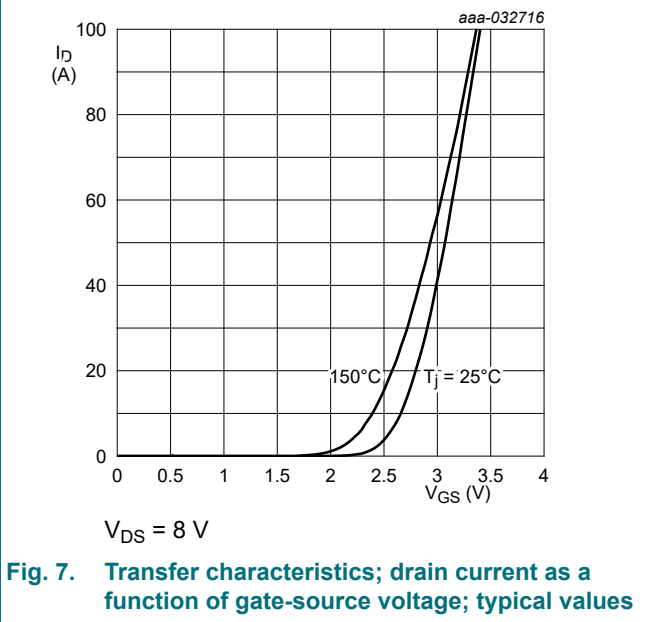
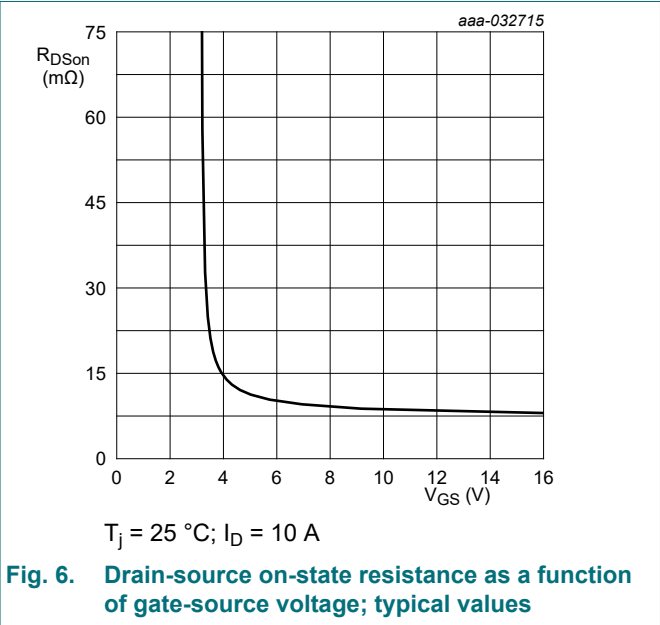
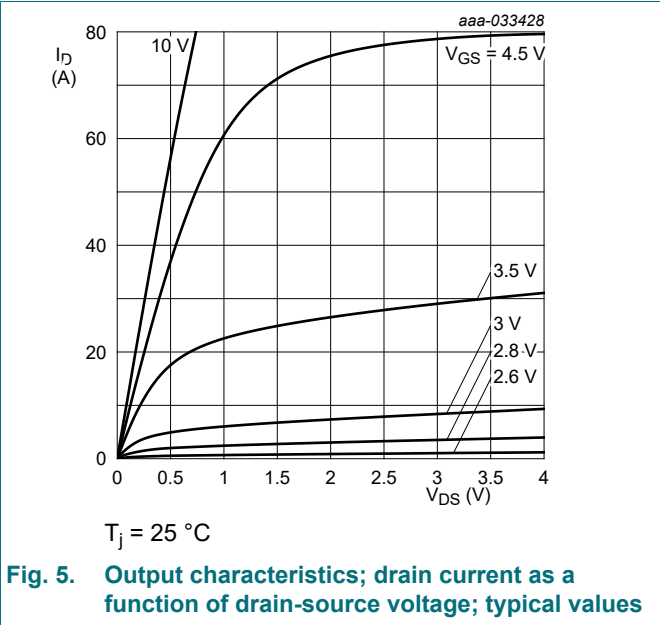
Table 7. Characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------------------|--|---|-----|-------|------|------------|
| Static characteristics | | | | | | |
| $V_{(BR)DSS}$ | drain-source breakdown voltage | $I_D = 250\ \mu A$; $V_{GS} = 0\ V$; $T_J = 25\ ^\circ C$ | 60 | 70 | - | V |
| | | $I_D = 250\ \mu A$; $V_{GS} = 0\ V$; $T_J = -55\ ^\circ C$ | - | 64 | - | V |
| $V_{GS(th)}$ | gate-source threshold voltage | $I_D = 1\ mA$; $V_{DS}=V_{GS}$; $T_J = 25\ ^\circ C$; Fig. 8 | 1.5 | 1.9 | 2.5 | V |
| | | $I_D = 1\ mA$; $V_{DS}=V_{GS}$; $T_J = 150\ ^\circ C$ | 0.9 | - | - | V |
| | | $I_D = 1\ mA$; $V_{DS}=V_{GS}$; $T_J = -55\ ^\circ C$ | - | - | 2.9 | V |
| $\Delta V_{GS(th)}/\Delta T$ | gate-source threshold voltage variation with temperature | $25\ ^\circ C \leq T_J \leq 150\ ^\circ C$ | - | -4.7 | - | mV/K |
| I_{DSS} | drain leakage current | $V_{DS} = 60\ V$; $V_{GS} = 0\ V$; $T_J = 25\ ^\circ C$ | - | 0.01 | 1 | μA |
| | | $V_{DS} = 60\ V$; $V_{GS} = 0\ V$; $T_J = 150\ ^\circ C$ | - | - | 500 | μA |
| I_{GSS} | gate leakage current | $V_{GS} = 20\ V$; $V_{DS} = 0\ V$; $T_J = 25\ ^\circ C$ | - | 2 | 100 | nA |
| | | $V_{GS} = -20\ V$; $V_{DS} = 0\ V$; $T_J = 25\ ^\circ C$ | - | 2 | 100 | nA |
| $R_{DS(on)}$ | drain-source on-state resistance | $V_{GS} = 10\ V$; $I_D = 10\ A$; $T_J = 25\ ^\circ C$; Fig. 9 | - | 9.8 | 11.5 | m Ω |
| | | $V_{GS} = 10\ V$; $I_D = 10\ A$; $T_J = 150\ ^\circ C$; Fig. 10 | - | - | 20 | m Ω |
| | | $V_{GS} = 4.5\ V$; $I_D = 10\ A$; $T_J = 25\ ^\circ C$; Fig. 9 | - | 14 | 17.6 | m Ω |
| | | $V_{GS} = 4.5\ V$; $I_D = 10\ A$; $T_J = 150\ ^\circ C$; Fig. 10 | - | - | 30 | m Ω |
| R_G | gate resistance | $f = 1\ MHz$; $T_J = 25\ ^\circ C$ | - | 1.66 | - | Ω |
| Dynamic characteristics | | | | | | |
| $Q_{G(tot)}$ | total gate charge | $I_D = 10\ A$; $V_{DS} = 30\ V$; $V_{GS} = 4.5\ V$; $T_J = 25\ ^\circ C$; Fig. 11 ; Fig. 12 | - | 9.64 | - | nC |
| | | $I_D = 10\ A$; $V_{DS} = 30\ V$; $V_{GS} = 10\ V$; $T_J = 25\ ^\circ C$; Fig. 11 ; Fig. 12 | - | 18.77 | - | nC |
| | | $I_D = 0\ A$; $V_{DS} = 0\ V$; $V_{GS} = 4.5\ V$; $T_J = 25\ ^\circ C$; Fig. 11 ; Fig. 12 | - | 9.54 | - | nC |
| Q_{GS} | gate-source charge | $I_D = 10\ A$; $V_{DS} = 30\ V$; $V_{GS} = 4.5\ V$; $T_J = 25\ ^\circ C$; Fig. 11 ; Fig. 12 | - | 3 | - | nC |
| $Q_{GS(th)}$ | pre-threshold gate-source charge | | - | 1.6 | - | nC |
| $Q_{GS(th-pl)}$ | post-threshold gate-source charge | | - | 1.4 | - | nC |
| Q_{GD} | gate-drain charge | | - | 4.3 | - | nC |
| $V_{GS(pl)}$ | gate-source plateau voltage | $I_D = 10\ A$; $V_{DS} = 30\ V$; $T_J = 25\ ^\circ C$; Fig. 11 ; Fig. 12 | - | 3.1 | - | V |
| C_{iss} | input capacitance | $V_{DS} = 30\ V$; $V_{GS} = 0\ V$; $f = 1\ MHz$; $T_J = 25\ ^\circ C$; Fig. 13 | - | 957 | - | pF |
| C_{oss} | output capacitance | | - | 386 | - | pF |
| C_{rss} | reverse transfer capacitance | | - | 31 | - | pF |
| $t_{d(on)}$ | turn-on delay time | $V_{DS} = 30\ V$; $R_L = 3\ \Omega$; $V_{GS} = 4.5\ V$; $R_{G(ext)} = 5\ \Omega$; $T_J = 25\ ^\circ C$ | - | 8.8 | - | ns |
| t_r | rise time | | - | 18.5 | - | ns |
| $t_{d(off)}$ | turn-off delay time | | - | 12.2 | - | ns |
| t_f | fall time | | - | 10.9 | - | ns |

N-channel 60 V, 11.5 mOhm, logic level Trench MOSFET in MLPAK33

| Symbol | Parameter | Conditions | | Min | Typ | Max | Unit |
|---------------------------|-----------------------|---|-----|-----|------|-----|------|
| Q_{oss} | output charge | $V_{GS} = 0\text{ V}$; $V_{DS} = 30\text{ V}$; $f = 1\text{ MHz}$; $T_j = 25\text{ }^{\circ}\text{C}$ | | - | 18 | - | nC |
| Source-drain diode | | | | | | | |
| V_{SD} | source-drain voltage | $I_S = 10\text{ A}$; $V_{GS} = 0\text{ V}$; $T_j = 25\text{ }^{\circ}\text{C}$; Fig. 14 | | - | 0.82 | 1.2 | V |
| t_{rr} | reverse recovery time | $I_S = 10\text{ A}$; $di_S/dt = -100\text{ A}/\mu\text{s}$; $V_{GS} = 0\text{ V}$; $V_{DS} = 30\text{ V}$; $T_j = 25\text{ }^{\circ}\text{C}$; Fig. 15 | | - | 22.1 | - | ns |
| Q_r | recovered charge | | [1] | - | 13 | - | nC |

[1] includes capacitive recovery



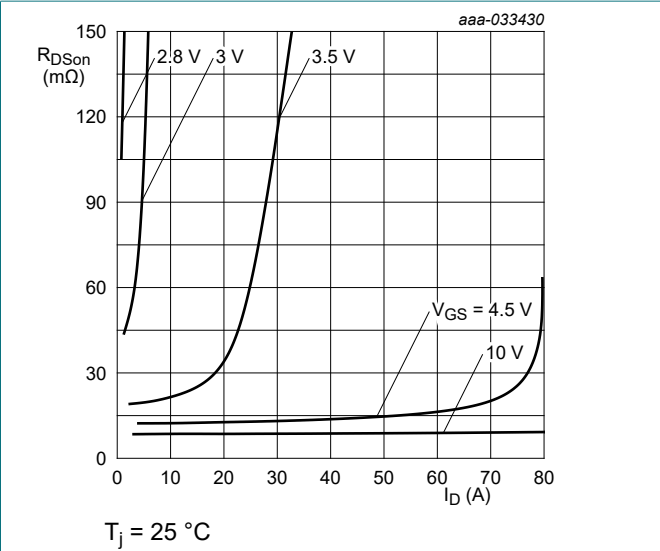


Fig. 9. Drain-source on-state resistance as a function of drain current; typical values

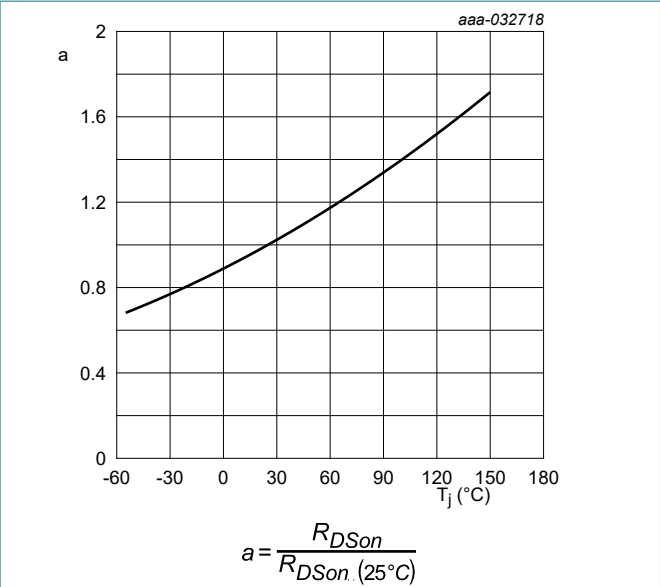


Fig. 10. Normalized drain-source on-state resistance factor as a function of junction temperature

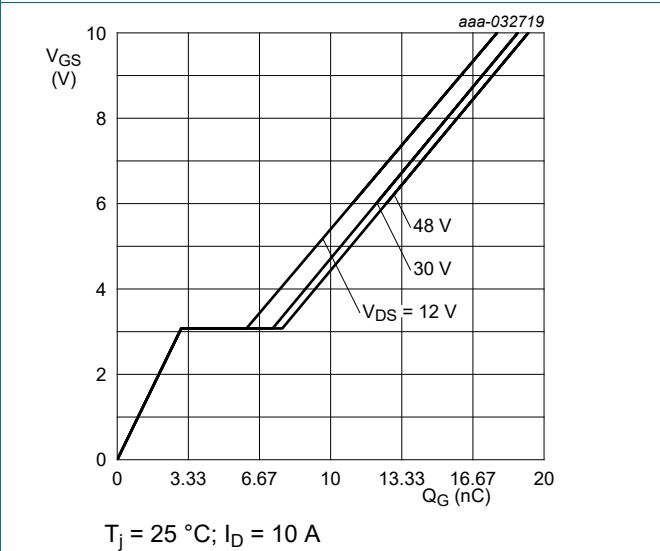


Fig. 11. Gate-source voltage as a function of gate charge; typical values

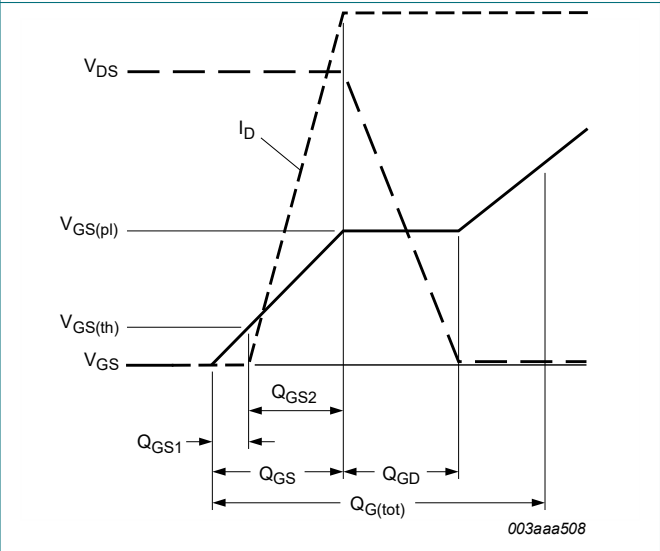


Fig. 12. Gate charge waveform definitions

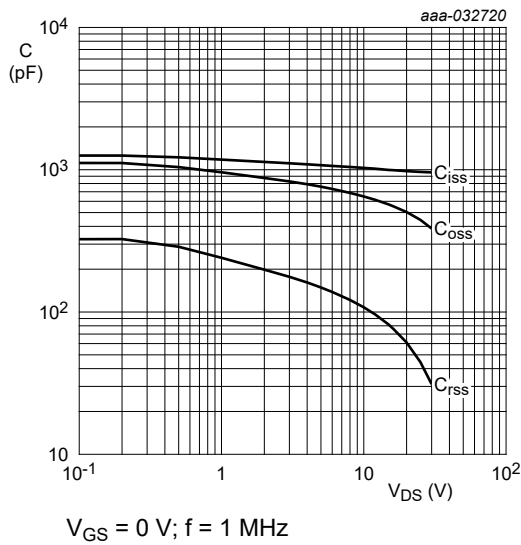


Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

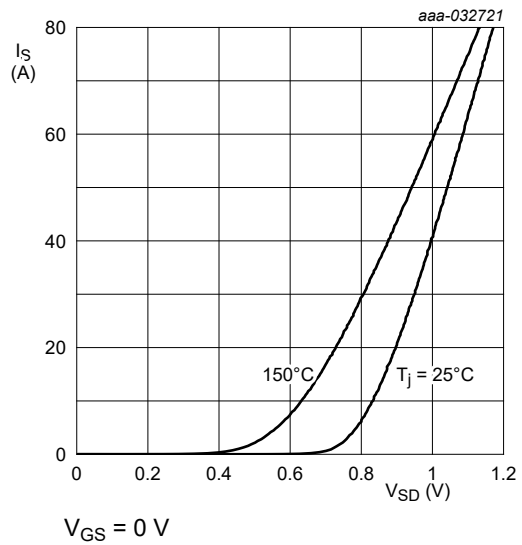


Fig. 14. Source-drain (diode forward) current as a function of source-drain (diode forward) voltage; typical values

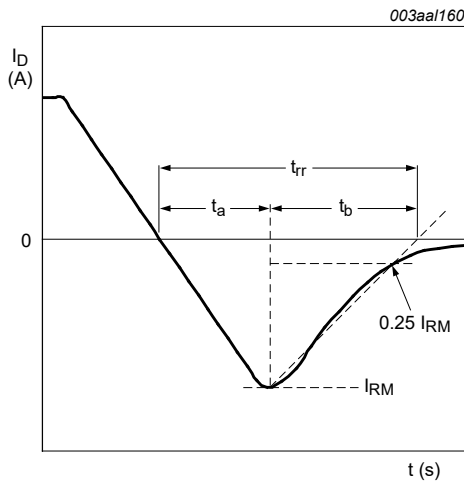


Fig. 15. Reverse recovery timing definition

11. Package outline

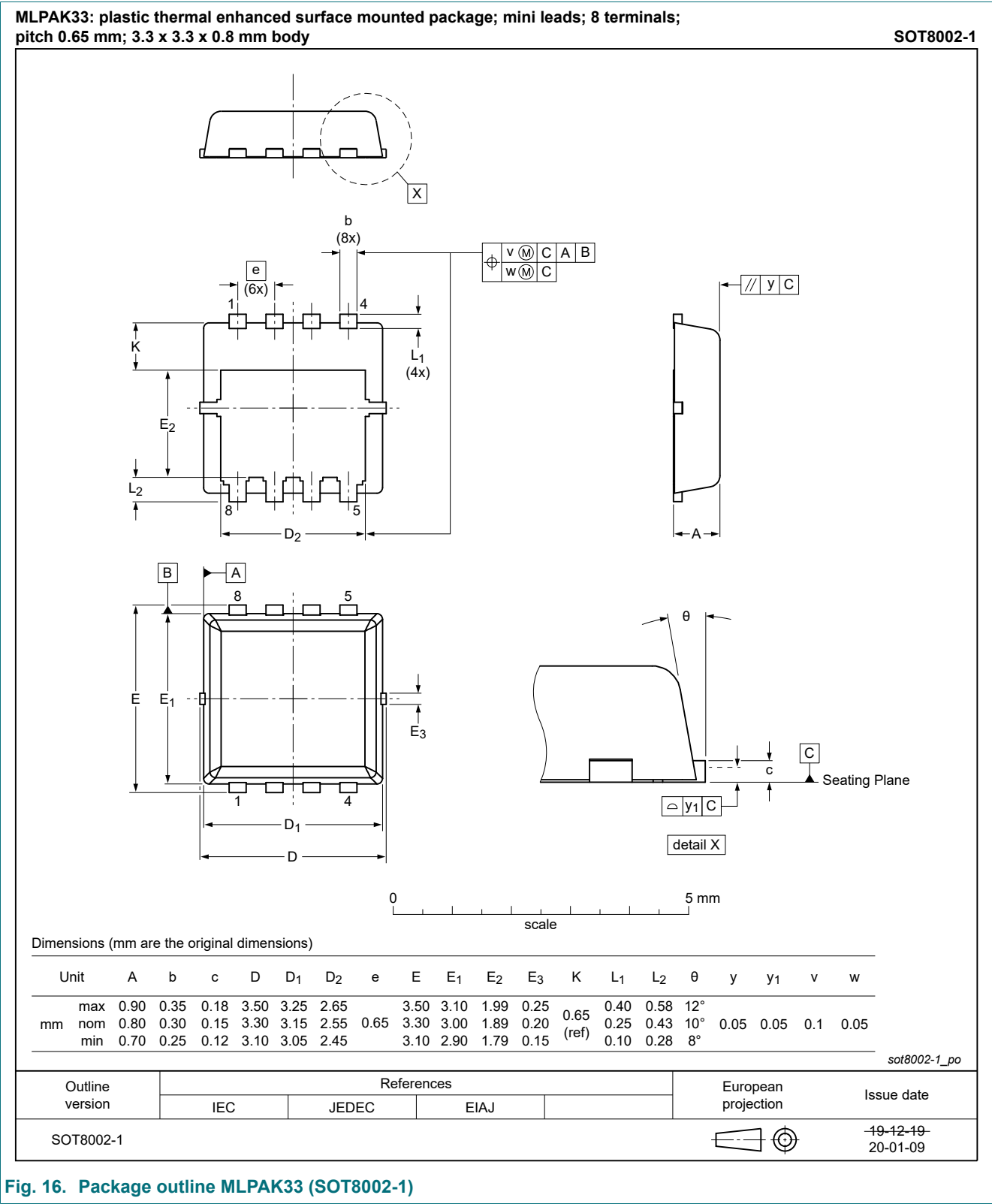


Fig. 16. Package outline MLPAK33 (SOT8002-1)

12. Soldering

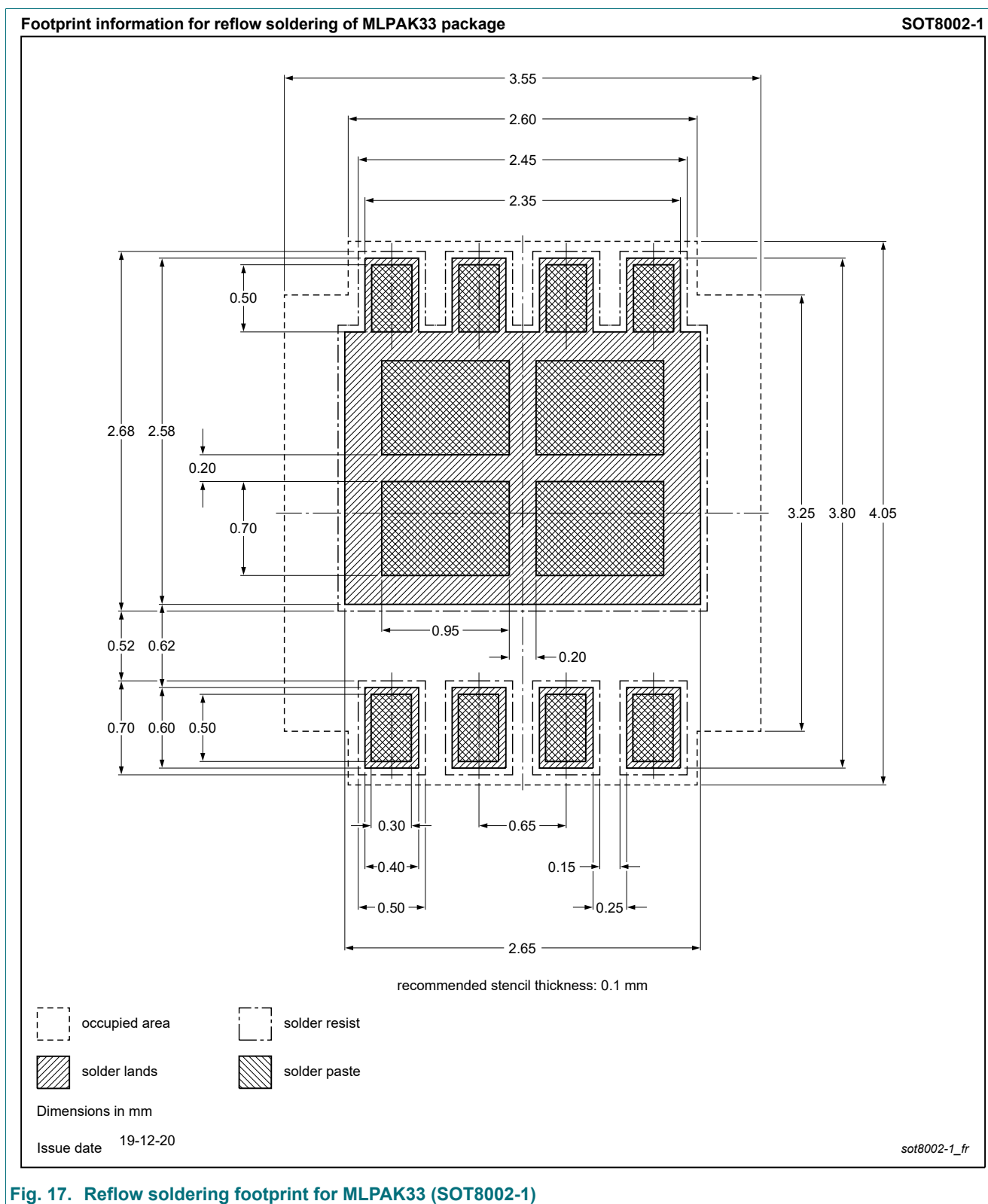


Fig. 17. Reflow soldering footprint for MLPAK33 (SOT8002-1)

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|--------------------------------|--------------------|---|
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| Product [short] data sheet | Production | This document contains the product specification. |

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- [2] The term 'short data sheet' is explained in section "Definitions".
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Date of release: 8 July 2021